A STATE OF A

查询LTC2050供应商 **LINEAR** TECHNOLOGY <u>ま业PCB打样IIIIIア料例</u>控制置LEASE Final Electrical Specifications LTC2050

Zero-Drift Operational Amplifier in SOT-23

November 1999

FEATURES

- SOT-23 Package
- Maximum Offset Voltage of 3µV
- Maximum Offset Voltage Drift of 30nV/°C
- Noise: 1.5µV_{P-P} (0.1Hz to 10Hz Typ)
- Voltage Gain: 140dB (Typ)
- PSRR: 130dB (Typ)
- CMRR: 130dB (Typ)
- Supply Current: 0.8mA (Typ)
- Single Supply Operation: 2.7V to 6V
- Extended Common Mode Input Range
- Output Swings Rail-to-Rail
- Overload Recovery Time: 2ms (Typ) 1

APPLICATIONS

- Thermocouple Amplifiers
- Electronic Scales
- Medical Instrumentation
- Strain Gauge Amplifiers
- High Resolution Data Acquisition

TYPICAL APPLICATION

DC Accurate RC Active Filters

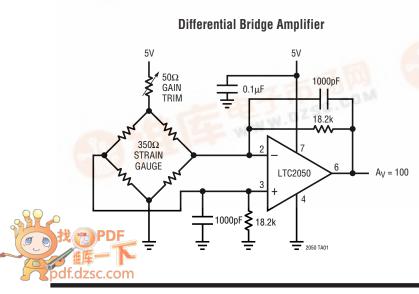
DESCRIPTION

The LTC[®]2050 is a low drift operational amplifier available in the 5- or 6-lead SOT-23 and SO-8 packages. It operates from a single 2.7V supply while still supporting 5V applications. The power consumption is 800µA and the versions in the 6-lead SOT-23 and SO-8 packages offer power shutdown (active low).

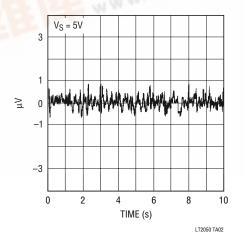
The LTC2050, despite its miniature size, features uncompromising DC performance. The typical input offset voltage and offset drift are 0.5μ V and $10nV/^{\circ}$ C. The almost zero DC offset and drift are supported with a power supply rejection ratio (PSRR) and common mode rejection ratio (CMRR) of more than 130dB.

The input common mode voltage ranges from the negative supply up to 1V from the positive supply. The LTC2050 also has an enhanced output stage capable of driving loads as low as $1k\Omega$ to both supply rails. The open-loop gain, loaded with $1k\Omega$, is in excess of 140dB. The LTC2050 also features a $1.5\mu V_{P-P}$ DC to 10Hz noise and a 3MHz gain bandwidth product.

T, LTC and LT are registered trademarks of Linear Technology Corporation.



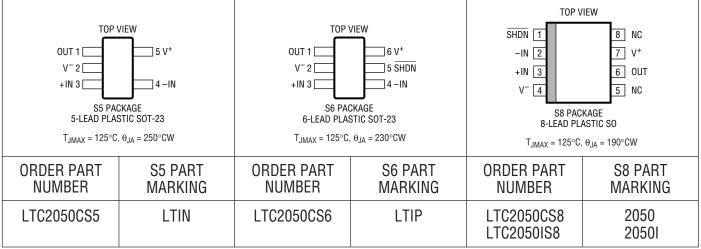
Input Referred Noise 0.1Hz to 10Hz



ABSOLUTE MAXIMUM RATINGS (Note 1)

 Specified Temperature Range (Note 3) ... -40° C to 85° C Storage Temperature Range -65° C to 150° C Lead Temperature (Soldering, 10 sec) 300° C

PACKAGE/ORDER INFORMATION



Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = 3V unless otherwise noted. (Note 3)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Input Offset Voltage	(Note 2)			±0.5	±3	μV
Average Input Offset Drift	(Note 2)	•			±0.03	μV/°C
Long-Term Offset Drift				50		nV/√mo
Input Bias Current				±20	±75	pА
		•			±300	pА
Input Offset Current					±150	рА
		•			±200	рА
Input Noise Voltage	$R_{\rm S}$ = 100 Ω , DC to 10Hz			1.5		μV _{P-P}
Common Mode Rejection Ratio	$V_{CM} = V^{-}$ to $V^{+} - 1.3$		115	130		dB
		•	110	130		dB
Power Supply Rejection Ratio			120	130		dB
		•	115	130		dB
Large-Signal Voltage Gain	$R_L = 10k$		120	140		dB
		•	115	140		dB
Maximum Output Voltage Swing	$R_L = 2k$	•	2.85	2.94		V
	R _L = 10k	•	2.95	2.98		V
Slew Rate				2		V/µs
Gain Bandwidth Product				3		MHz
Supply Current	V _{SHDN} = V ⁺ , No Load	•		0.75	1.1	mA
	$V_{SHDN} = V^{-}$				10	μA

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = 3V unless otherwise noted. (Note 3)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Shutdown Pin Input Low Voltage		•			V ⁻ + 0.5	V
Shutdown Pin Input High Voltage		•	V ⁺ - 0.5			V
Shutdown Pin Input Current	$V_{SHDN} = V^{-}$	•		-0.5	-3	μA
Internal Sampling Frequency				7.5		kHz

The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. V_S = 5V unless otherwise noted. (Note 3)

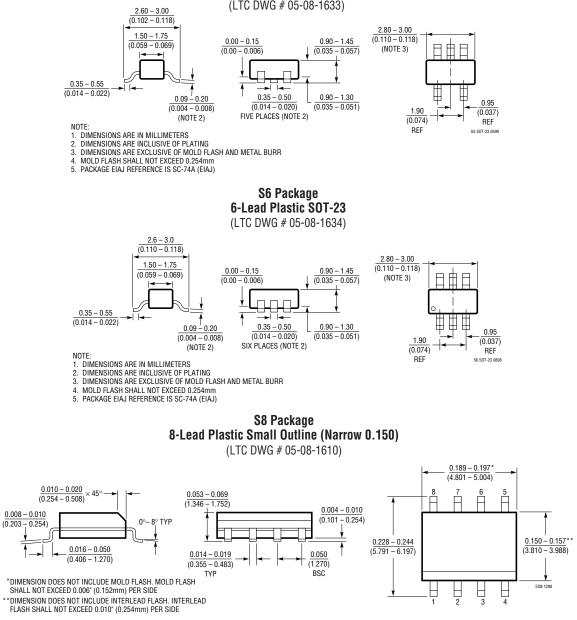
PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Input Offset Voltage	(Note 2)			±0.5	±3	μV
Average Input Offset Drift	(Note 2)	•			±0.03	μV/°C
Long-Term Offset Drift				50		nV/√mo
Input Bias Current					±150	pA
					±300	рА
Input Offset Current					±300	рA
					±400	рА
Input Noise Voltage	$R_S = 100\Omega$, DC to 10Hz			1.5		μV _{P-P}
Common Mode Rejection Ratio	$V_{CM} = V^{-}$ to $V^{+} - 1.3$		120	130		dB
			115	130		dB
Power Supply Rejection Ratio			120	130		dB
			115	130		dB
Large-Signal Voltage Gain	$R_L = 10k$		125	140		dB
		•	120	140		dB
Maximum Output Voltage Swing	$R_L = 2k$		4.85	4.94		V
	R _L = 10k	•	4.95	4.98		V
Slew Rate				2		V/µs
Gain Bandwidth Product				3		MHz
Supply Current	V _{SHDN} = V ⁺ , No Load	•		0.8	1.2	mA
	$V_{SHDN} = V^{-}$				10	μA
Shutdown Pin Input Low Voltage		•			V ⁻ + 0.5	V
Shutdown Pin Input High Voltage		•	V ⁺ -0.5			V
Shutdown Pin Input Current	$V_{SHDN} = V^{-}$	•		-0.5	-5	μA
Internal Sampling Frequency				7.5		kHz

Note 1: Absolute Maximum Ratings are those values beyond which the life of the device may be impaired.

Note 2: These parameters are guaranteed by design. Thermocouple effects preclude measurements of these voltage levels during automated testing.

Note 3: The LTC2050C is guaranteed to meet specified performance from 0°C to 70°C and is designed, characterized and expected to meet these extended temperature limits, but is not tested at -40°C and 85°C. The LTC2050I is guaranteed to meet the extended temperature limits.

PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted. S5 Package 5-Lead Plastic S0T-23 (LTC DWG # 05-08-1633)



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1049	Low Power Zero-Drift Op Amp	Low Supply Current 200µA
LTC1050	Precision Zero-Drift Op Amp	Single Supply Operation 4.75V to 16V, Noise Tested and Guaranteed
LTC1051/LTC1053	Precision Zero-Drift Op Amp	Dual/Quad
LTC1150	±15V Zero-Drift Op Amp	High Voltage Operation ±18V
LTC1152	Rail-to-Rail Input and Output Zero-Drift Op Amp	Single Zero-Drift Op Amp with Rail-to-Rail Input and Output and Shutdown